## : ©hipsmall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts,Customers Priority,Honest Operation, and Considerate Service",our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!


## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832
Email \& Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, \#122 Zhenhua RD., Futian, Shenzhen, China

## lotted Optical Flag itch pe OPB690



## Features

- Phototransistor output
- Mechanical switch replacement
- 3-pin connector (Ho Tien L2561-03), Molex compatible connector 5102 series housing and 5103 series terminal
- Enhanced signal to noise ratio


## Description

The OPB690 consists of an NPN phototransistor and an infrared emitting diode in a molded plastic housing. The phototransistor has an enhanced low current roll-off which improves contrast ratio and immunity to background irradiance. A lever arm actuated flag interrupts the light beam, switching the transistor output between states that can readily drive logic gates.

This switch is designed to easily snap mount into a $0.037{ }^{\prime \prime} \pm 0.001$ " ( 0.94 mm ) thick material with a rectangular opening of $0.320^{\prime \prime} \pm 0.003$ " x 0.472 " ( $8.13 \mathrm{~mm} \times$ 11.99 mm ) minimum. Insertion into the punched side of metal is recommended.

Customized lever arms and spring torques can be designed for specific applications.


Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)
Storage and Operating Temperature . . . . . . . . . . . . . . . . . . . . . . . $-40^{\circ} \mathrm{C}$ to $+100^{\circ} \mathrm{C}$

## Input Diode

Forward DC Current . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 50 mA
Peak Forward Current ( 1 s pulse width, 300 pps) . . . . . . . . . . . . . . . . . . . . . . 3. 3 A
Reverse DC Voltage. . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 3.0 3.0 V
Power Dissipation . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 100 mW ${ }^{(1)}$
Output Phototransistor
Collector-Emitter Voltage. . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 30 V
Emitter Reverse Current. . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 10 mA
Collector DC Current . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 30 mA
Power Dissipation . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 200 mW ${ }^{(2)}$

## Notes:

(1) Derate linearly $1.33 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $25^{\circ} \mathrm{C}$.
(2) Derate linearly $2.0 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $25^{\circ} \mathrm{C}$.
(3) "Off" condition exists when the lever arm is in the rest position ( $20^{\circ}$ from vertical) as shown in the figure.
(4) "On" condition exists when the lever arm is deflected clockwise $18^{\circ}+/-3^{\circ}$ form the rest position ( $20^{\circ}$ from vertical) as shown in the figure.
(5) From the rest position to the switch point, lever torque measured at the end of the arm is 1.5 grams max.


For RoHS compliant devices add " $Z$ " to the end of the part number: OPB690Z

RoHS

## Type OPB690

Electrical Characteristics ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| SYMBOL | PARAMETER | MIN | MAX | UNITS | TEST CONDITIONS |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Input Diode |  |  |  |  |  |
| $V_{F}$ | Forward Voltage |  | 1.6 | V | $\mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}$ |
| $\mathrm{I}_{\mathrm{R}}$ | Reverse Current |  | 100 | $\mu \mathrm{A}$ | $\mathrm{V}_{\mathrm{R}}=3.0 \mathrm{~V}$ |
| Output Phototransistor |  |  |  |  |  |
| $V_{\text {(BR)CEO }}$ | Collector-Emitter Breakdown Voltage | 30 |  | V | $\mathrm{IC}=100 \mu \mathrm{~A}$ |
| Ieco | Emitter Reverse Current |  | 100 | $\mu \mathrm{A}$ | $\mathrm{V}_{\mathrm{EC}}=0.4 \mathrm{~V}$ |
| Iceo | Collector-Emitter Dark Current |  | 100 | nA | $V_{C E}=5 \mathrm{~V}$ |
| Coupled |  |  |  |  |  |
| Vsat | Saturation Voltage |  | 0.4 | V | $\mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}, \mathrm{I}_{\mathrm{C}}=100 \mu \mathrm{~A}$, Gap unblocked |
| IC(ON) | On-State Collector Current | 600 |  | $\mu \mathrm{A}$ | $\mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}, \mathrm{~V}_{\text {CE }}=5 \mathrm{~V}$ |



